

## SSCP3906GSG

### **Dual PNP Switching Transistor**

#### > Features

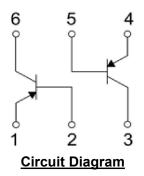
VCB	VCE	VBE	IC
-40V	-40V	-5V	-200mA

#### > Description

The NPN Transistor is designed for use in linear and switching applications. The device is housed in the SOT-363 package, which is designed for telephony and professional communication equipment.

# Pin configuration



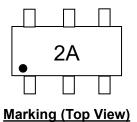


### > Applications

- General purpose switching and amplification
- Epitaxial planar die construction

### > Ordering Information

Device	Package	Shipping
SSCP3906GSG	SOT-363	3000/Reel





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### > Absolute Maximum Ratings ( $T_A = 25^{\circ}C$ unless otherwise noted)

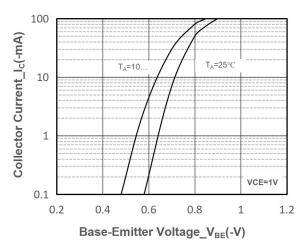
Parameter	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-40	V
Collector- Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5	V
Collector Current-Continuous	lc	-200	mA
Collector Power Dissipation	Pc	200	mW
Junction Temperature	TJ	625	°C
Storage Temperature	T <sub>STG</sub>	-55 to 150	°C

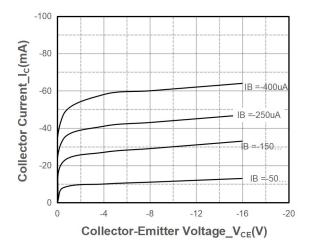
### > Electrical Characteristics ( $T_A=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Collector-Base Breakdown Voltage	ВУсво	Ic=-10uA, I <sub>E</sub> =0	-40			V
Collector-emitter Breakdown Voltage	BVCEO	I <sub>C</sub> =-1mA, I <sub>B</sub> =0	-40			V
Emitter -Base Breakdown Voltage	BV <sub>EBO</sub>	I <sub>E</sub> =-10uA, I <sub>C</sub> =0	-5			V
Collector Cutoff Current	ICEX	V <sub>CE</sub> =-30V, V <sub>EB</sub> =-3V			0.05	uA
Collector Cutoff Current	Ісво	V <sub>CB</sub> =-30V, I <sub>E</sub> =0			0.05	uA
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =-5V, I <sub>C</sub> =0			0.05	uA
		V <sub>CE</sub> = -1V, I <sub>C</sub> =-0.1mA	60			
DC Current Gain		V <sub>CE</sub> =-1V, I <sub>C</sub> =-1mA	80			
	h <sub>FE</sub>	V <sub>CE</sub> =-1V, I <sub>C</sub> =-10mA	100		300	
		V <sub>CE</sub> =-1V, I <sub>C</sub> =-50mA	60			
		V <sub>CE</sub> =-1V, I <sub>C</sub> =-100mA	30			
	V <sub>CE (sat)1</sub>	I <sub>C</sub> =-10mA, I <sub>B</sub> =-1mA			-0.25	V
Collector-Emitter Saturation Voltage	mitter Saturation Voltage V <sub>CE (sat)2</sub> I <sub>C</sub> =-5	I <sub>C</sub> =-50mA, I <sub>B</sub> =-5mA			-0.4	V
	V <sub>BE (sat)1</sub>	I <sub>C</sub> =-10mA, I <sub>B</sub> =-1mA	-0.65		-0.85	V
Base-Emitter Saturation Voltage	V <sub>BE (sat)2</sub>	I <sub>C</sub> =-50mA, I <sub>B</sub> =-5mA			-0.95	V
<b>—</b> <i>r</i>	fT	V <sub>CE</sub> =-20V, I <sub>C</sub> =-10mA	050			MHz
Transition frequency		f=100MHz	250			
		VCB=-5V, IE=0,			4.5	_
Collector output capacitance	Cob	f=1MHz			4.5	pF
Nuite a firmuna		VCE=-5V, lc=-0.1mA,				
Noise figure	NF	f=1kHz, RS=1KΩ 4 dB	a B			
	V <sub>CC</sub> =-3V, V <sub>BE (off)</sub> =0.5V					
Delay Time	t <sub>d</sub>	I <sub>C</sub> =-10mA, I <sub>B1</sub> =-1mA			35 ns	
	ne   t <sub>r</sub>	V <sub>CC</sub> =-3V, V <sub>BE (off)</sub> =0.5V		35		ns
Rise Time		I <sub>C</sub> =-10mA, I <sub>B1</sub> =-1mA			35	
Storago Timo	4	V <sub>cc</sub> =-3V, I <sub>c</sub> =-10mA			225	ns
Storage Time	ts	I <sub>B1</sub> = -I <sub>B2</sub> =-1mA				
Fall Time	t.	V <sub>CC</sub> =-3V, I <sub>C</sub> =-10mA			75	ns
	t <sub>f</sub>	I <sub>B1</sub> = -I <sub>B2</sub> =-1mA				

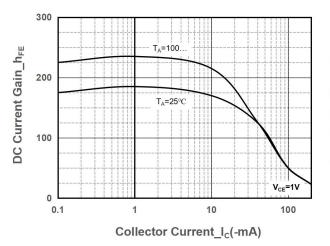


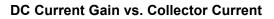
### Typical Performance Characteristics (TA=25°C unless otherwise noted)

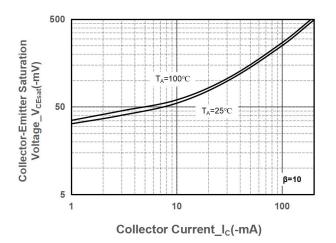






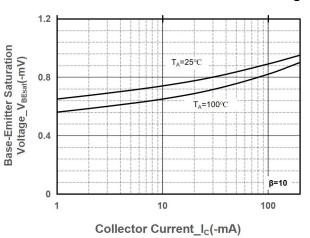




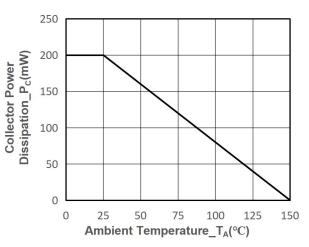




Collector Current vs. Collector-Emitter Voltage



VBE(sat) vs. Collector Current



Power derating vs. Ambient temperature

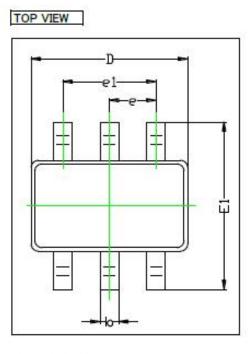


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### > Package Information

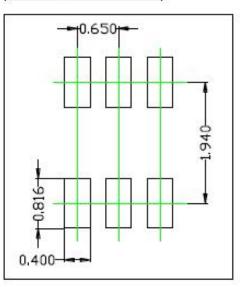
FRONT VIEW

<u>SOT-363</u>



SOLDRING PATTERN

SIDE VIEW



SYMBOL	DIMENSIONS IN MILLIMETER		
	MIN	MAX	
Α	0.900	1.000	
A1	0.000	0.100	
A2	0.900	1.000	
b	0.150	0.300	
С	0.100	0.150	
D	2.000	2.200	
E	1.150	1.350	
E1	2.150	2.400	
е	0.6	50 TYP.	
e1	1.200	1.400	
	0.525 REF.		
L1	0.260	0.450	
θ	0*	8*	

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